

Supplementary materials for “Exploring the Photocatalytic Properties and Carrier Dynamics of 2D Janus XMMX’ (X=S, Se; M = Ga, In; and X’ =Te) Materials”

Bofeng Zhang¹, Akang Li¹, Jiahe Lin², WanZhen Liang^{1,}*

¹ State Key Laboratory of Physical Chemistry of Solid Surfaces, Collaborative Innovation Center of Chemistry for Energy Materials, Fujian Provincial Key Laboratory of Theoretical and Computational Chemistry, and Department of Chemistry, College of Chemistry and Chemical Engineering, Xiamen University, Xiamen 361005, Fujian Province, People’s Republic of China

² School of Science, Jimei University, Xiamen 361021, Fujian Province, People’s Republic of China

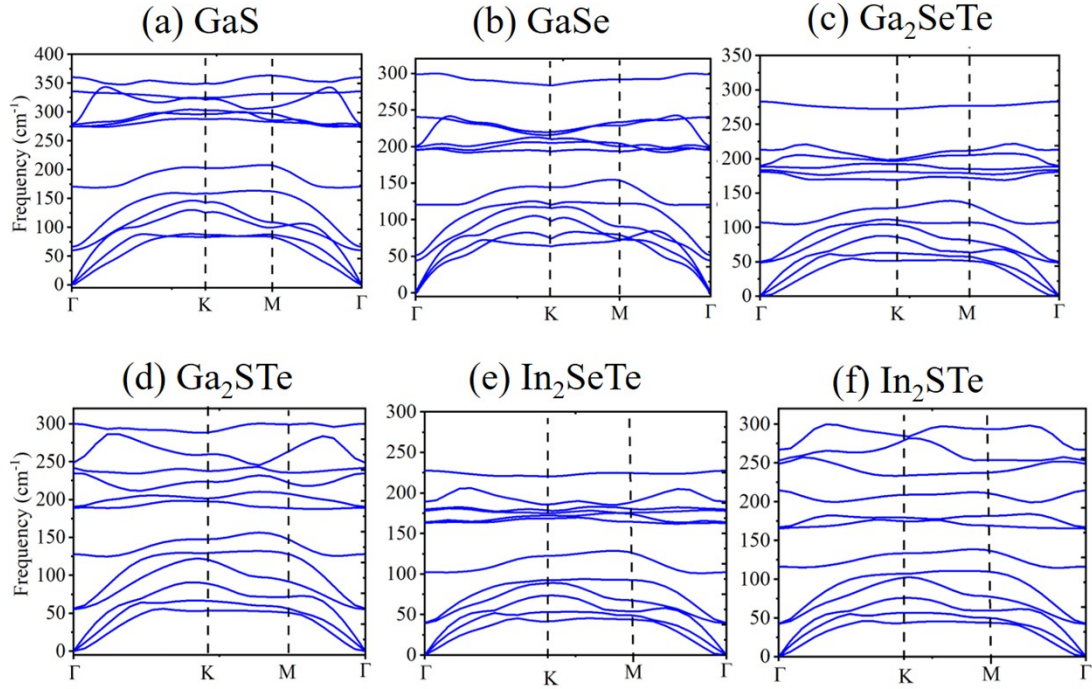


Fig. S1. (a)-(f) the phonon spectra of GaS, GaSe, Ga₂SeTe, Ga₂STe, In₂SeTe and In₂STe, respectively.

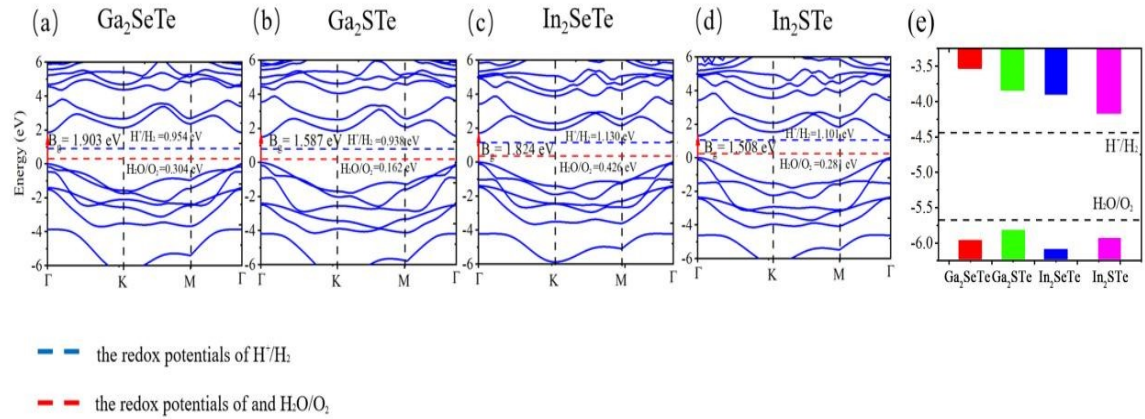


Fig. S2. (a)-(d) The band structures of Ga₂SeTe, Ga₂STe, In₂SeTe and In₂STe calculated by DFT with XC functional HSE06, compared with the standard redox potentials for water splitting shown as pink dashed lines and blue dashed lines, respectively. (e) the GW calculated band edge of Ga₂SeTe, Ga₂STe, In₂SeTe and In₂STe.

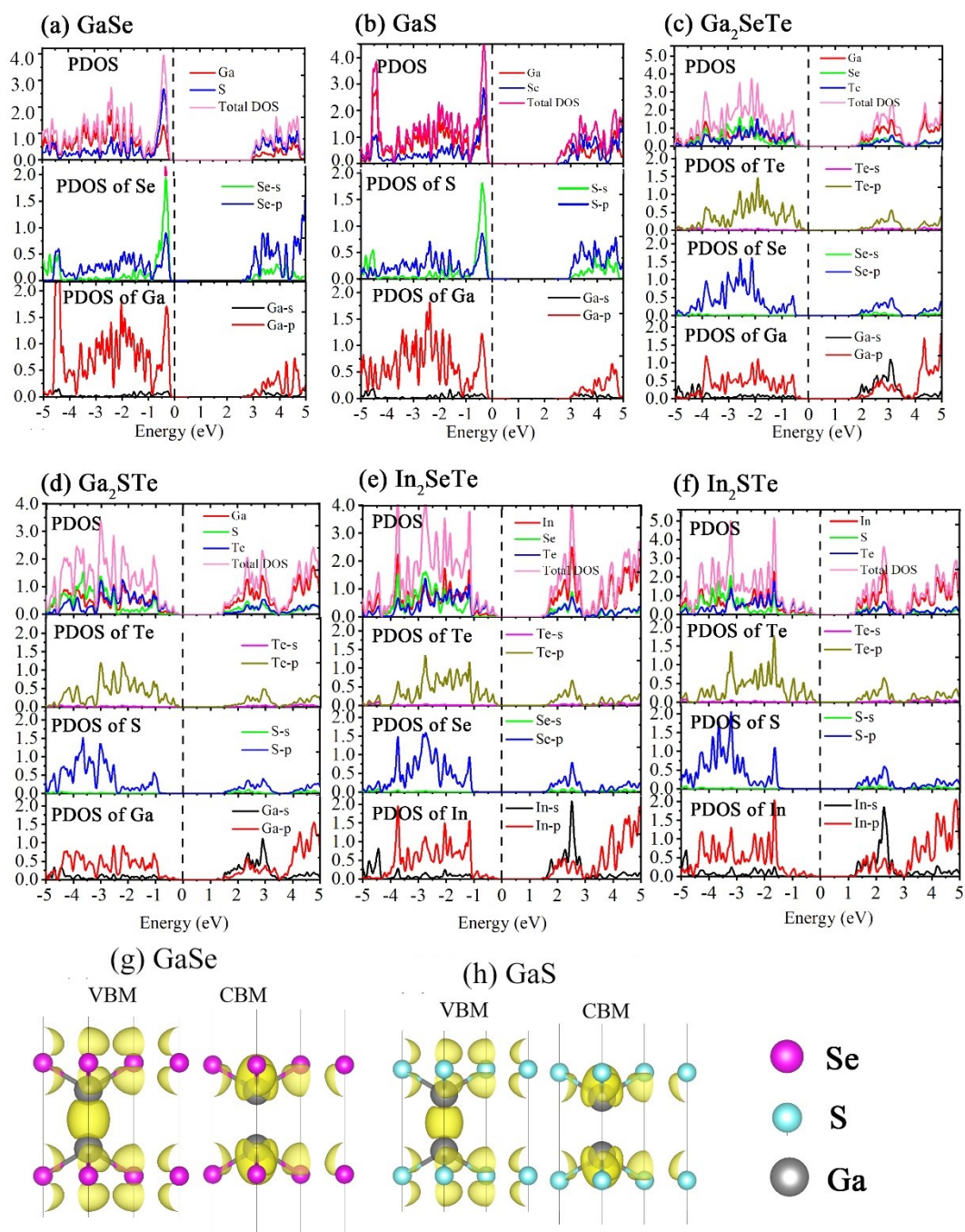


Fig. S3. (a)-(f) The PDOS of Janus XMMX' and pristine MX monolayers. (g) and (h) charge density of CBM (right) and VBM (left) of GaSe and GaS.

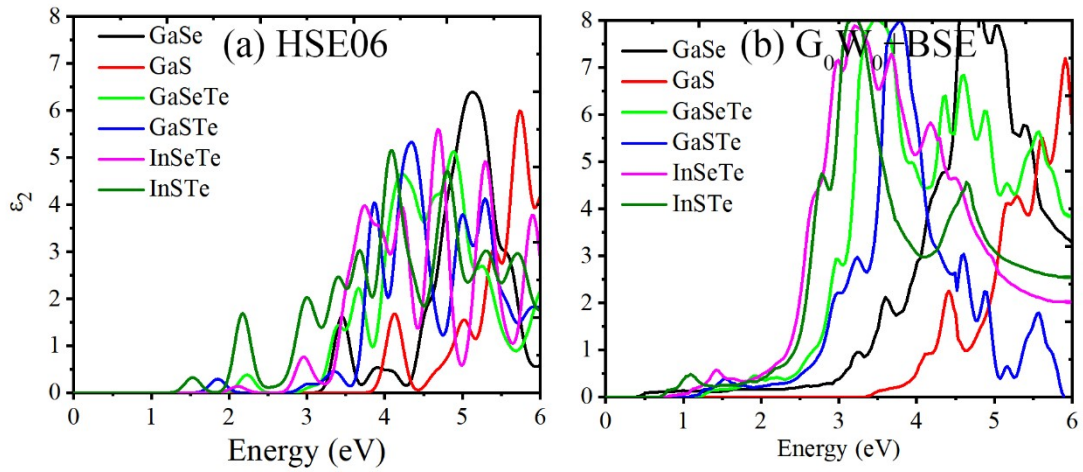


Fig. S4. (a) and (b) Imaginary parts of the dielectric functions of GaSe, GaS, Ga₂SeTe, Ga₂STe, In₂SeTe and In₂STe calculated by the independent particle model with HSE06 and the GW+BSE approach, respectively.

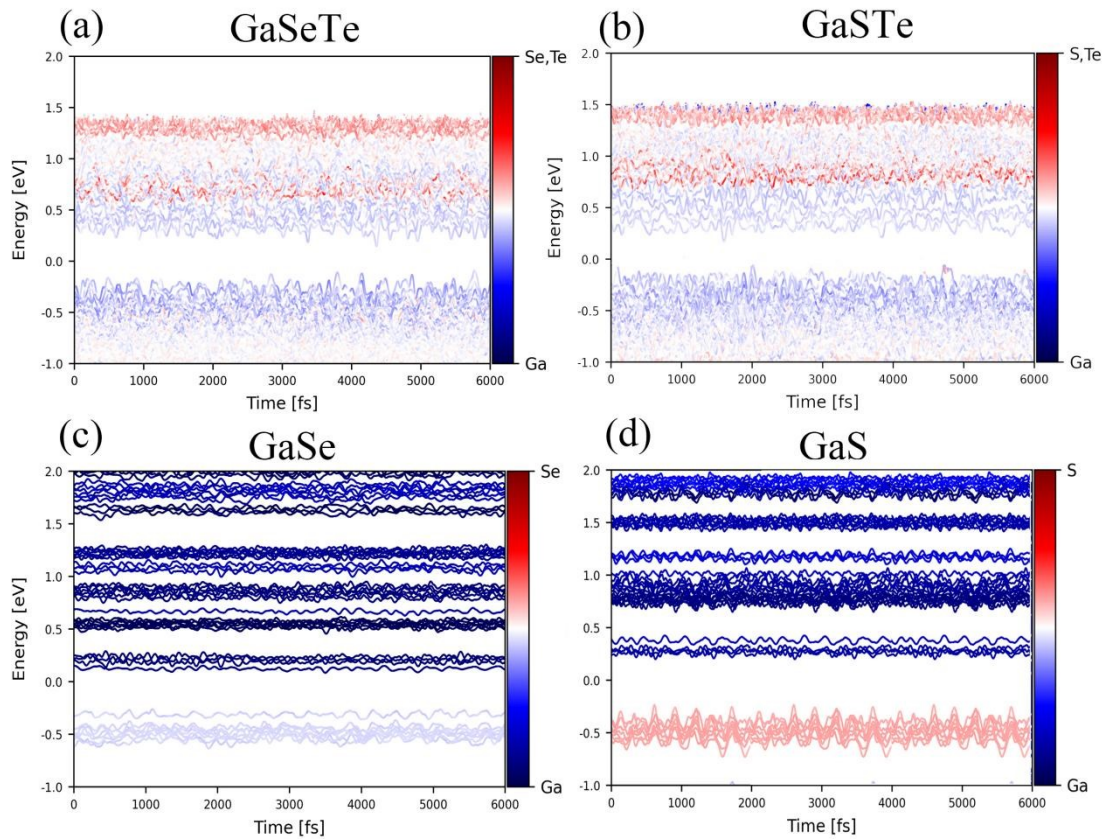


Fig. S5 (a)-(d) Time evolutions of the energy states for the Ga₂SeTe, Ga₂STe, GaSe and GaS, respectively, and the color map indicates the orbital localization. The red lines and blue lines stand for the contribution from X and X' atoms and M atoms, respectively.

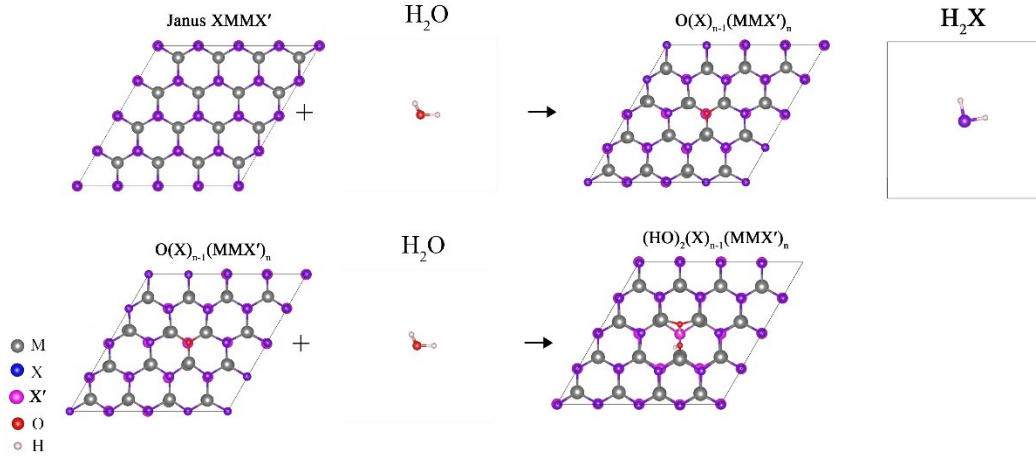


Fig. S6 Diagram of hydration reaction of Janus XMMX'.

Table SI Calculated formation enthalpy, ΔH (in eV), for the hydration reaction of Janus XMMX'. Here $H_A = H_{O(X)_{n-1}(MMX')_n} + H_{H_2S} - H_{XMMX'} - H_{H_2O}$. $H_B = H_{(HO)_2(X)_{n-1}(MMX')_n} - H_{O(X)_{n-1}(MMX')_n} - H_{H_2O}$ and $\Delta H = H_A + H_B$.

	H_A	H_B	ΔH
Ga ₂ SeTe	49.027	8.7772	57.8042
Ga ₂ STe	50.431	8.3285	58.7595
In ₂ SeTe	9.157	6.9261	16.0831
In ₂ STe	10.932	6.5423	17.4743

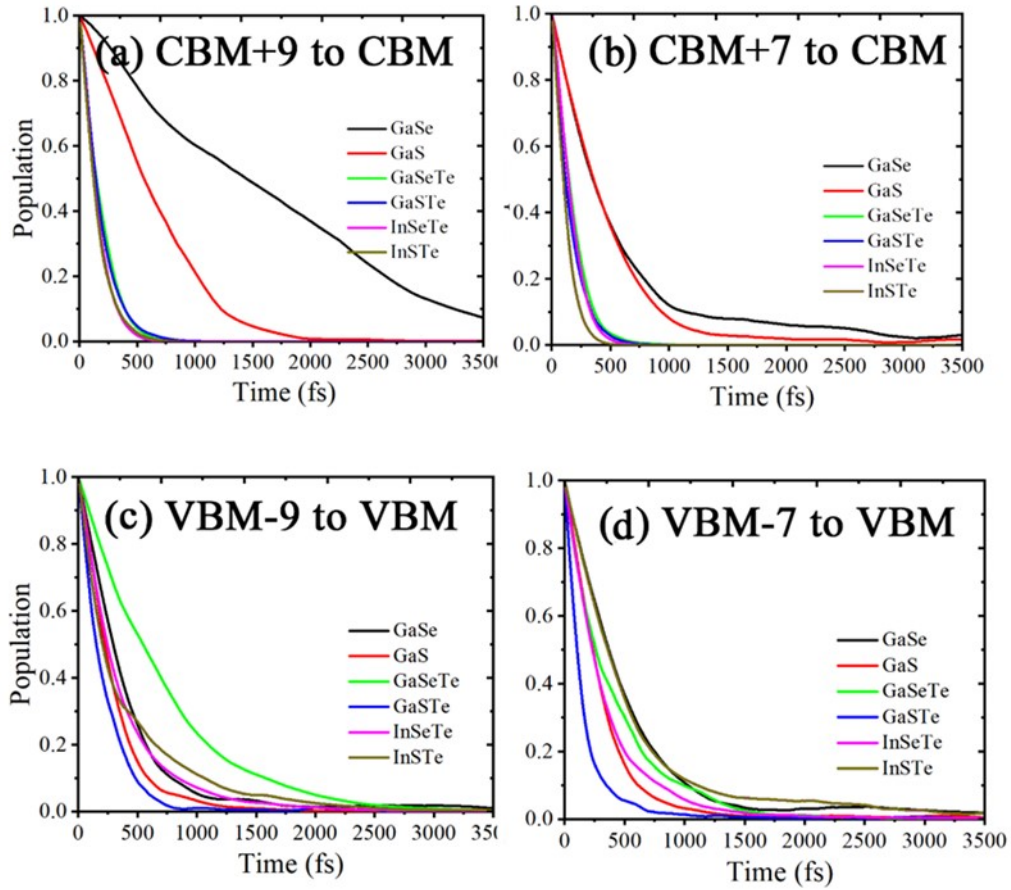


Fig. S7 (a)(b) Electron relaxation dynamics from CBM+9 and CBM+7 to CBM in Janus XMMX' and pristine MX. (c)(d) Hole relaxation dynamics from VBM-9 and VBM-7 to VBM in Janus XMMX' and pristine MX.